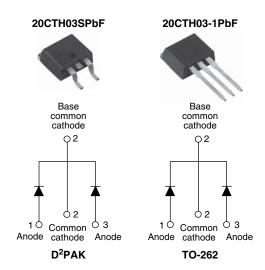




Vishay High Power Products

## Hyperfast Rectifier, 2 x 10 A FRED Pt<sup>TM</sup>



PRODUCT SUMMARY				
t <sub>rr</sub> (maximum)	35 ns			
I <sub>F(AV)</sub>	2 x 10 A			
$V_{R}$	300 V			

#### **FEATURES**

- · Hyperfast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for Q101 level

#### **DESCRIPTION/APPLICATIONS**

300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, dc-to-dc converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS
Peak repetitive reverse voltage		V <sub>RRM</sub>		300	V
Average rectified forward current —	per diode		T <sub>C</sub> = 160 °C	10	
	per device	IF(AV)		20	Α
Non-repetitive peak surge current		I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	120	
Operating junction and storage temperatures		T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	300	-	-		
Forward voltage V <sub>F</sub>		I <sub>F</sub> = 10 A	-	1.05	1.25	V	
	I <sub>F</sub> = 10 A, T <sub>J</sub> = 125 °C	-	0.85	0.95			
Devenue leeke ve enweet		$V_R = V_R$ rated	-	-	20		
Reverse leakage current I <sub>R</sub>		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{ rated}$	-	6	200	μΑ	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 300 V	-	30	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH	

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<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply

# 20CTH03SPbF/20CTH03-1PbF

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt =$	50 A/μs, V <sub>R</sub> = 30 V	-	-	35	
Boyaraa raaayary tima		$I_F = 1.0 \text{ A}, dI_F/dt =$	100 A/ $\mu$ s, V <sub>R</sub> = 30 V	-	-	30	no
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	31	-	ns
		T <sub>J</sub> = 125 °C		-	42	-	
Peak recovery current		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 10 A dI <sub>F</sub> /dt = 200 A/μs	-	2.4	-	Α
	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$V_{\rm R} = 200 \text{ V}$	-	5.6	-	
Reverse recovery charge	0	T <sub>J</sub> = 25 °C	] ''	-	36	-	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	120	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C
Thermal resistance, junction to case per diode	R <sub>thJC</sub>		-	-	1.5	°C/W
Weight			-	2.0	=	g
weight		-	0.07	-	OZ.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Madinadaria		Case style D <sup>2</sup> PAK		20CTH03S		
Marking device		Case style TO-262		20CT	H03-1	



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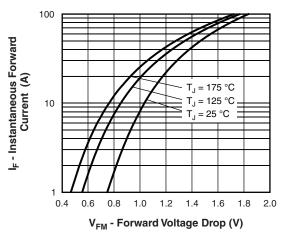


Fig. 1 - Maximum Forward Voltage Drop Characteristics

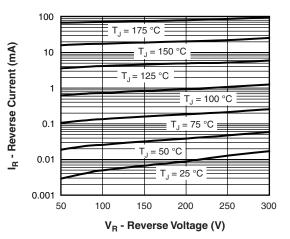


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

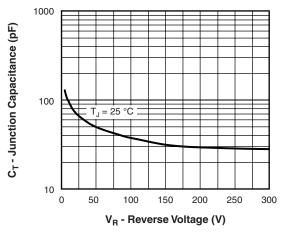


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

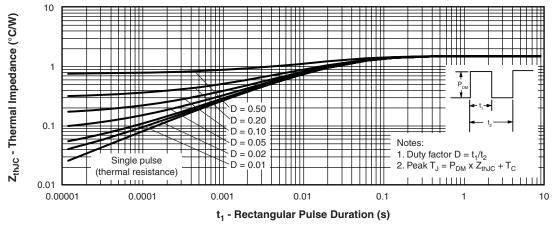


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

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## 20CTH03SPbF/20CTH03-1PbF

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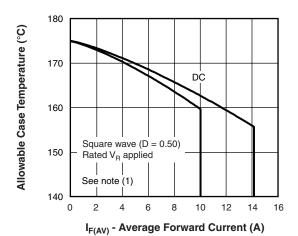


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

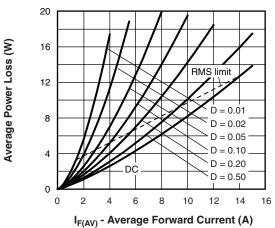
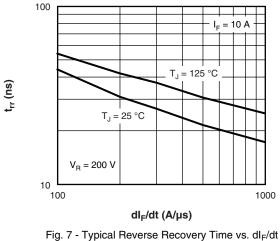


Fig. 6 - Forward Power Loss Characteristics



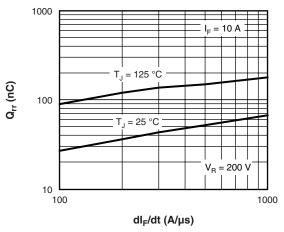


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \text{(1)} \;\; \text{Formula used:} \; T_C = T_J - (Pd + Pd_{REV}) \; x \; R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \; x \; V_{FM} \; \text{at} \; (I_{F(AV)}/D) \; (\text{see fig. 6}); \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \; x \; I_R \; (1 - D); \; I_R \; \text{at} \; V_{R1} = \text{Rated} \; V_R \\ \end{array}$ 



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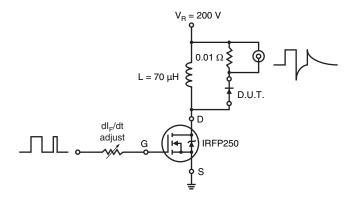
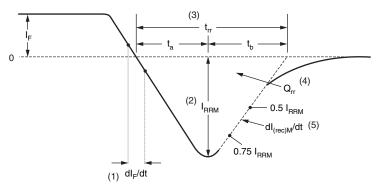


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $t_{\rm rr}$  reverse recovery time measured from zero crossing point of negative going  $I_{\rm F}$  to point where a line passing through 0.75  $I_{\rm RRM}$  and 0.50  $I_{\rm RRM}$  extrapolated to zero current.
- (4)  $Q_{rr}$  area under curve defined by  $t_{rr}$  and  $I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

## 20CTH03SPbF/20CTH03-1PbF

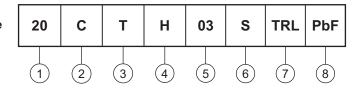
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#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Current rating (20 A)

2 - C = Common cathode

 $T = TO-220, D^2PAK$ 

4 - H = Hyperfast rectifier

Voltage rating (03 = 300 V)

6 - • S = D<sup>2</sup>PAK

• -1 = TO-262

7 - • None = Tube (50 pieces)

• TRL = Tape and reel (left oriented, for D<sup>2</sup>PAK package)

• TRR = Tape and reel (right oriented, for D<sup>2</sup>PAK package)

8 - • None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95014			
Part marking information	http://www.vishay.com/doc?95008			
Packaging information	http://www.vishay.com/doc?95032			



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Revision: 18-Jul-08

Document Number: 91000 www.vishay.com